

IRFI644G

IRFI644G Information

er Vishay Siliconix Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
MOSFET N-CH 250V 7.9A TO220FP
TO-220-3 Full Pack, Isolated Tab
For the pricing/inventory/lead time, please contact
us
Website: https://www.heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IRFI644G Specifications

Manufacturer Part Number	IRFI644G
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3 Full Pack, Isolated Tab
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	250V
Current - Continuous Drain (Id) @ 25°C	7.9A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	68nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1300pF @ 25V
Vgs (Max)	$\pm 20\mathrm{V}$
FET Feature	-
Power Dissipation (Max)	40W (Tc)
Rds On (Max) @ Id, Vgs	280 mOhm @ 4.7A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	ТО-220-3
Package / Case	TO-220-3 Full Pack, Isolated Tab
	Report errors?

IRFI644G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about IRFI644G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com